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U.S. PATENT DOCUMENTS

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	A					
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FOREIGN PATENT DOCUMENTS

	Document No.	Date	Country	Class	Subclass	Translation
No Copies	L	1-11411	05/1989	JAPAN		Cited on ISR
	M	2-52514	02/1990	JAPAN		Cited on ISR
	N	2003-209449	10/2003	JAPAN		Cited on ISR
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	Q					

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

/BS/	R	Schloemann et al., "Epitaxial Fe films on GaAs for hybrid semiconductor-magnetic memories", 04/1988, pages 3140-3142 (Cited in Specification English Text) Journal of Applied Physics
	S	Vol. 63, No. 8
	T	

Examiner: /Barbara Summons/

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